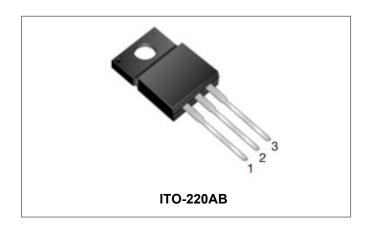






STF2050C SCHOTTKY RECTIFIER



Features

- 150 °C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	50	٧
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=95°C, rectangular wave form	10(Per Leg) 20(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, Tc=25°C	80	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*	V _{F1}	@ 5A, Pulse, T _J = 25 °C @ 10A, Pulse, T _J = 25 °C	0.43 0.49	- 0.55	V
	V _{F2}	 @ 5A, Pulse, T_J = 125 °C @ 10A, Pulse, T_J = 125 °C 	0.34 0.44	- 0.49	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	0.01	1.5	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	9	85	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	400	-	pF
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, T _A = 25 °C)		Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	
,	V _{ISO}	Clip mounting, the epoxy body is inside the heatsink.	-	3500	V
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

Pulse width < 300 μs, duty cycle < 2%

- China Germany Korea Singapore United States
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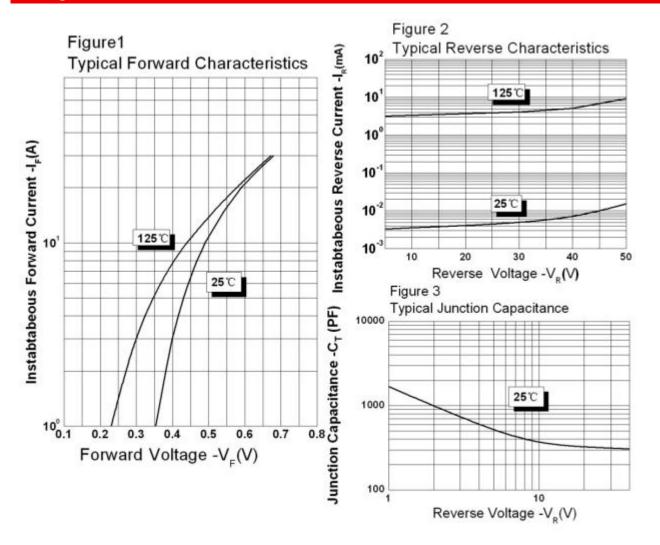




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ heta JC}$	DC operation	6	°C/W
Approximate Weight	wt	- 2		g
Case Style	ITO-220AB			

Ratings and Characteristics Curves



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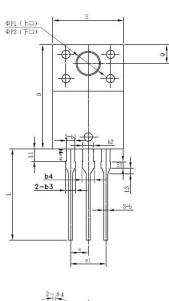
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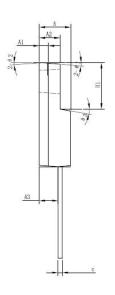






Mechanical Dimensions ITO-220AB

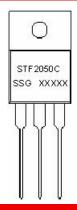






SYMBOL	Millimeters			
STWIDOL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
<u>L1</u>	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦΡ1(├ □)	3.30	3.50	3.70	
ΦP2 (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

Marking Diagram



Where XXXXX is YYWWL

 ST
 = Device Type

 F
 = Package type

 20
 = Forward Current (20A)

 50
 = Reverse Voltage (50V)

 C
 = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Tube Specification



Ordering Information

Device	Package	Shipping
STF2050C	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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